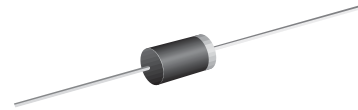




General Purpose Plastic Rectifier

Major Ratings and Characteristics

$I_{F(AV)}$	1.0 A
V_{RRM}	50 V to 1000 V
I_{FSM}	50 A
I_R	1.0 μ A
V_F	1.0 V, 1.1 V
T_j max.	150 °C



DO-204AL (DO-41)

Features

- Low forward voltage drop
- Low leakage current
- High forward surge capability
- Solder Dip 260 °C, 40 seconds



Mechanical Data

Case: DO-204AL, molded epoxy body

Epoxy meets UL-94V-0 Flammability rating

Terminals: Matte tin plated (E3 Suffix) leads, solderable per J-STD-002B and JESD22-B102D

Polarity: Color band denotes cathode end

Typical Applications

For use in general purpose rectification of power supplies, inverters, converters and freewheeling diodes application.

(Note: These devices are not Q101 qualified. Therefore, the devices specified in this datasheet have not been designed for use in automotive or Hi-Rel applications.)

Maximum Ratings

($T_A = 25\text{ °C}$ unless otherwise noted)

Parameter	Symbol	M100A	M100B	M100D	M100G	M100J	M100K	M100M	Unit
Maximum repetitive peak reverse voltage	V_{RRM}	50	100	200	400	600	800	1000	V
Maximum RMS voltage	V_{RMS}	35	70	140	280	420	560	700	V
Maximum DC blocking voltage	V_{DC}	50	100	200	400	600	800	1000	V
Maximum average forward rectified current 0.375" (9.5 mm) lead length at $T_A = 100\text{ °C}$	$I_{F(AV)}$	1.0							A
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load	I_{FSM}	50							A
Maximum full load reverse current full cycle average 0.375" (9.5 mm) lead length at $T_A = 55\text{ °C}$	$I_{R(AV)}$	100							μ A
Operating junction and storage temperature range	T_J, T_{STG}	- 50 to + 150							°C

M100A thru M100M



Vishay General Semiconductor

Electrical Characteristics

($T_A = 25\text{ }^\circ\text{C}$ unless otherwise noted)

Parameter	Test condition	Symbol	M100A	M100B	M100D	M100G	M100J	M100K	M100M	Unit	
Maximum instantaneous forward voltage	at 1.0 A	V_F	1.0						1.1		V
Maximum DC reverse current at rated DC blocking voltage	$T_A = 25\text{ }^\circ\text{C}$ $T_A = 100\text{ }^\circ\text{C}$	I_R	1.0 50								μA
Typical reverse recovery time	at $I_F = 0.5\text{ A}$, $I_R = 1.0\text{ A}$, $I_{rr} = 0.25\text{ A}$	t_{rr}	2.0								μs
Typical junction capacitance	at 4.0 V, 1 MHz	C_J	15								pF

Thermal Characteristics

($T_A = 25\text{ }^\circ\text{C}$ unless otherwise noted)

Parameter	Symbol	M100A	M100B	M100D	M100G	M100J	M100K	M100M	Unit	
Typical thermal resistance ⁽¹⁾	$R_{\theta JA}$ $R_{\theta JL}$	50 25								$^\circ\text{C/W}$

Note: (1) Thermal resistance from junction to ambient and from junction to lead at 0.375" (9.5 mm) lead length, P.C.B. mounted

Ratings and Characteristics Curves

($T_A = 25\text{ }^\circ\text{C}$ unless otherwise noted)

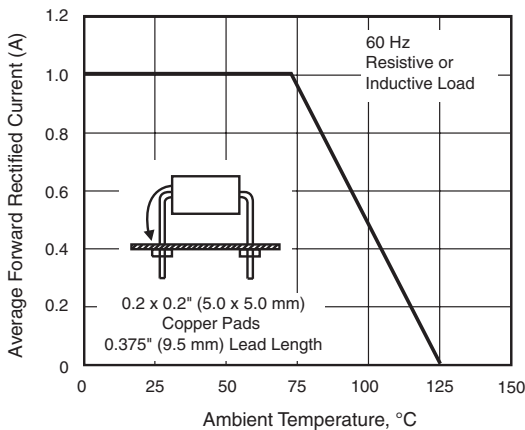


Figure 1. Forward Current Derating Curve

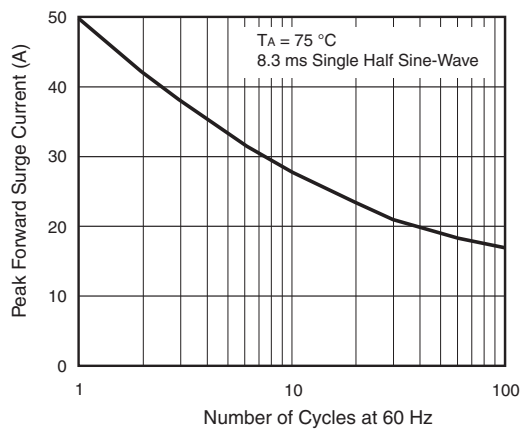


Figure 2. Maximum Non-repetitive Peak Forward Surge Current

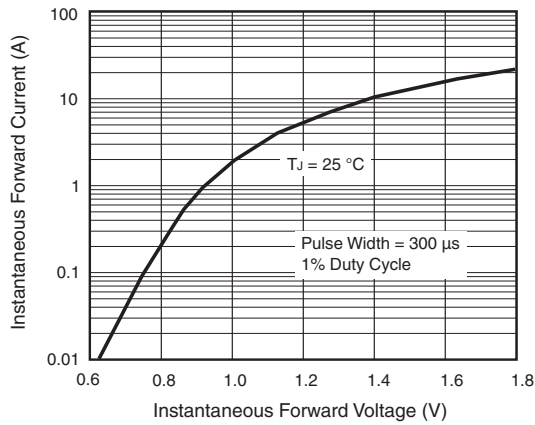


Figure 3. Typical Instantaneous Forward Characteristics

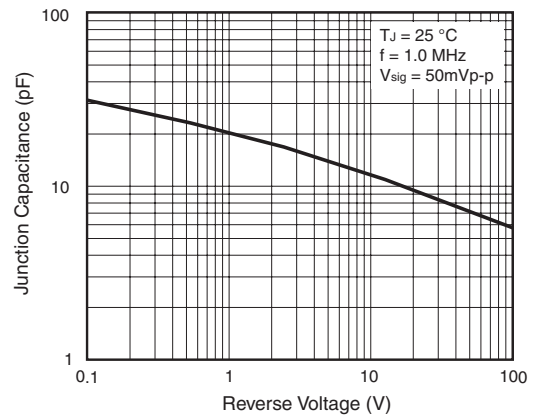


Figure 5. Typical Junction Capacitance

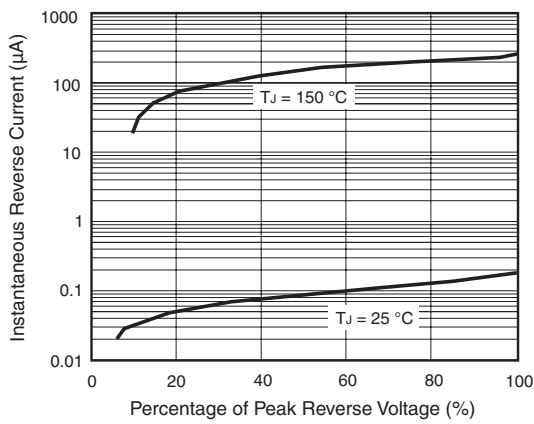


Figure 4. Typical Reverse Characteristics

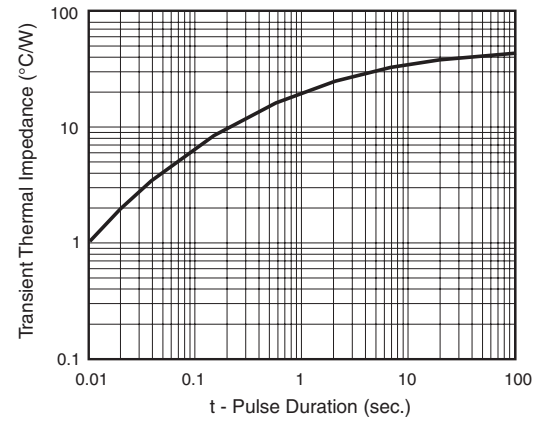


Figure 6. Typical Transient Thermal Impedance

Package outline dimensions in inches (millimeters)

